



# **DMMT3904W**

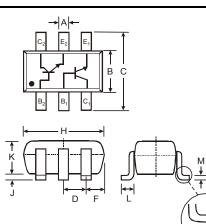
### MATCHED NPN SMALL SIGNAL SURFACE MOUNT TRANSISTOR

#### Features

- Epitaxial Planar Die Construction .
- Intrinsically Matched NPN Pair (Note 1) •
- Small Surface Mount Package
- 2% Matched Tolerance, hFE, VCE(SAT), VBE(SAT)
- Lead Free/RoHS Compliant (Note 3)
- "Green" Device (Note 4 and 5)

### **Mechanical Data**

- Case: SOT-363
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C .
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- Terminal Connections: See Diagram
- Marking Information: See Page 4
- Ordering & Date Code Information: See Page 4
- Weight: 0.015 grams (approximate)



SOT-363								
Dim	Min	Max						
Α	0.10	0.30						
в	1.15	1.35						
С	2.00	2.20						
D	0.65 Nominal							
F	0.30	0.40						
н	1.80	2.20						
J	_	0.10						
к	0.90 1.00							
L	0.25	0.40						
М	0.10	0.25						
α	0°	8°						
All Dimensions in mm								

#### Maximum Ratings @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic		Symbol	Value	Unit		
Collector-Base Voltage		V <sub>CBO</sub>	60	V		
Collector-Emitter Voltage		V <sub>CEO</sub>	40	V		
Emitter-Base Voltage		V <sub>EBO</sub>	6.0	V		
Collector Current - Continuous		lc	200	mA		
Power Dissipation	(Note 2)	Pd	200	mW		
Thermal Resistance, Junction to Ambient	(Note 2)	$R_{ ext{ heta}JA}$	625	°C/W		
Operating and Storage Temperature Range		T <sub>j</sub> , T <sub>STG</sub>	-55 to +150	°C		

Notes: Built with adjacent die from a single wafer. 1.

Device mounted on FR5 PCB: 1.0 x 0.75 x 0.62 in.; pad layout as shown on suggested pad layout document AP02001, 2.

which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

No purposefully added lead. 3.

4.

Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead\_free/index.php. Product manufactured with Date Code UO (week 40, 2007) and newer are built with Green Molding Compound. Product manufactured prior to Date 5. Code UO are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.

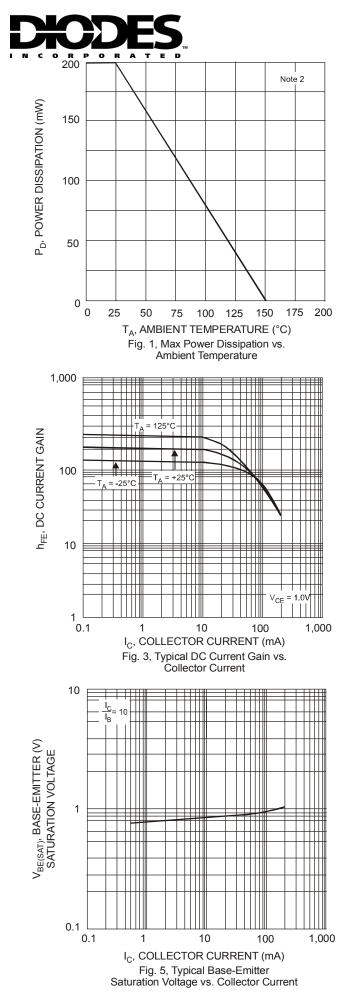


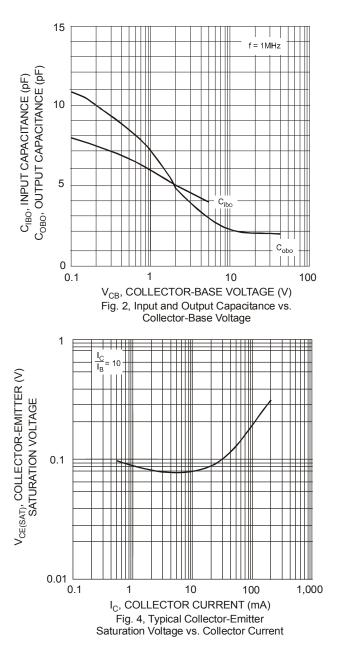
**Electrical Characteristics** @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Symbol Min			Test Condition			
OFF CHARACTERISTICS (Note 6)		•	,	•	,			
Collector-Base Breakdown Voltage	V <sub>(BR)CBO</sub>	60	_	V	$I_{\rm C}$ = 10 $\mu$ A, $I_{\rm E}$ = 0			
Collector-Emitter Breakdown Voltage	V <sub>(BR)CEO</sub>	40	_	V	$I_{\rm C}$ = 1.0mA, $I_{\rm B}$ = 0			
Emitter-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	6.0	_	V	$I_{\rm E} = 10 \mu A, I_{\rm C} = 0$			
Collector Cutoff Current	I <sub>CEX</sub>	—	50	nA	V <sub>CE</sub> = 30V, V <sub>EB(OFF)</sub> = 3.0V			
Base Cutoff Current	I <sub>BL</sub>	_	50	nA	V <sub>CE</sub> = 30V, V <sub>EB(OFF)</sub> = 3.0V			
ON CHARACTERISTICS (Note 6)	·	•						
DC Current Gain (Note 7)	h <sub>FE</sub>	40 70 100 60 30	 300 		$\begin{split} I_{C} &= 100 \mu A, \ V_{CE} &= 1.0 V \\ I_{C} &= 1.0 m A, \ V_{CE} &= 1.0 V \\ I_{C} &= 10 m A, \ V_{CE} &= 1.0 V \\ I_{C} &= 50 m A, \ V_{CE} &= 1.0 V \\ I_{C} &= 100 m A, \ V_{CE} &= 1.0 V \end{split}$			
Collector-Emitter Saturation Voltage (Note 7)	V <sub>CE(SAT)</sub>	—	0.20 0.30	v	$I_{C}$ = 10mA, $I_{B}$ = 1.0mA $I_{C}$ = 50mA, $I_{B}$ = 5.0mA			
Base-Emitter Saturation Voltage (Note 7)	V <sub>BE(SAT)</sub>	0.65	0.85 0.95	V	$I_{C}$ = 10mA, $I_{B}$ = 1.0mA $I_{C}$ = 50mA, $I_{B}$ = 5.0mA			
Base-Emitter Voltage Matching	$\Delta V_{BE}$	—	1	mV	V <sub>CE</sub> = 5V, I <sub>C</sub> = 2mA			
SMALL SIGNAL CHARACTERISTICS								
Output Capacitance	C <sub>obo</sub>		4.0	pF	V <sub>CB</sub> = 5.0V, f = 1.0MHz, I <sub>E</sub> = 0			
Input Capacitance	C <sub>ibo</sub>	—	8.0	pF	$V_{EB}$ = 0.5V, f = 1.0MHz, I <sub>C</sub> = 0			
Input Impedance	h <sub>ie</sub>	1.0	10	kΩ				
Voltage Feedback Ratio	h <sub>re</sub>	0.5	8	x 10⁻⁴	V <sub>CE</sub> = 10V, I <sub>C</sub> = 1.0mA,			
Small Signal Current Gain	h <sub>fe</sub>	100	400	_	f = 1.0kHz			
Output Admittance	h <sub>oe</sub>	1.0	40	μS				
Current Gain-Bandwidth Product	f <sub>T</sub>	300	_	MHz	V <sub>CE</sub> = 20V, I <sub>C</sub> = 10mA, f = 100MHz			
Noise Figure	NF	_	5.0	dB	$V_{CE} = 5.0V, I_C = 100\mu A,$ R <sub>S</sub> = 1.0k $\Omega$ , f = 1.0kHz			
SWITCHING CHARACTERISTICS	·	·	•					
Delay Time	t <sub>d</sub>		35	ns	V <sub>CC</sub> = 3.0V, I <sub>C</sub> = 10mA,			
Rise Time	tr	—	35	ns	V <sub>BE(off)</sub> = -0.5V, I <sub>B1</sub> = 1.0mA			
Storage Time	ts	—	200	ns	V <sub>CC</sub> = 3.0V, I <sub>C</sub> = 10mA,			
Fall Time	tf	_	50	ns	$I_{B1} = I_{B2} = 1.0 \text{mA}$			

Notes: 6. Short duration pulse test used to minimize self-heating effect.

7. The DC current gain,  $h_{FE}$ , (matched at  $I_C = 10$ mA and  $V_{CE} = 1.0$ V) Collector Emitter Saturation Voltage,  $V_{CE(SAT)}$ , and Base Emitter Saturation Voltage,  $V_{BE(SAT)}$  are matched with typical matched tolerances of 1% and maximum of 2%.





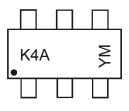


#### Ordering Information (Note 8)

Device	Packaging	Shipping		
DMMT3904W-7-F	SOT-363	3000/Tape & Reel		

Notes: 8. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

## **Marking Information**



K4A = Product Type Marking Code YM = Date Code Marking Y = Year ex: T = 2006 M = Month ex: 9 = September

Date Code Key

Year	2002	2003	2004	200	5 20	06	2007	20	800	2009	2010	2011	2012
Code	N	Р	R	S	-	Г	U	١	V	W	Х	Y	Z
							- 1			1	4		1
Month	Jan	Feb	Mar	Apr	Мау	Jur	ı J	ul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	-	7	8	9	0	Ν	D

#### IMPORTANT NOTICE

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to any product herein. Diodes Incorporated does not assume any liability arising out of the application or use of any product described herein; neither does it convey any license under its patent rights, nor the rights of others. The user of products in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on our website, harmless against all damages.

LIFE SUPPORT

Diodes Incorporated products are not authorized for use as critical components in life support devices or systems without the expressed written approval of the President of Diodes Incorporated.